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RC4580QDRQ1

Texas instruments

Audio Amplifiers Dual Audio Op Amp

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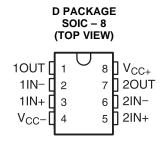


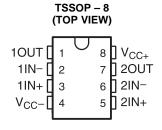
DUAL AUDIO OPERATIONAL AMPLIFIER

Check for Samples: RC4580-Q1

FEATURES

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
 - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C3B
- Operating Voltage . . . ±2 V to ±18 V
- Low Noise Voltage . . . 0.8 μVrms (TYP)
- Wide GBW . . . 12 MHz (TYP)
- Low THD . . . 0.0005% (TYP)
- Slew Rate . . . 5 V/µs (TYP)
- Suitable for Automotive Applications Such As Audio Preamplifier, Active Filter, Headphone Amplifier, Industrial Measurement Equipment
- Drop-In Replacement for NJM4580
- Pin and Function Compatible With LM833, NE5532, NJM4558/9, and NJM4560/2/5





PW PACKAGE

DESCRIPTION

The RC4580-Q1 device is a dual operational amplifier that is designed optimally for audio applications, such as improving tone control. It offers low noise, high gain bandwidth, low harmonic distortion, and high output current. All of these features make the device ideally suited for audio electronics, such as audio preamplifiers and active filters, as well as industrial measurement equipment. When high output current is required, the RC4580-Q1 device can be used as a headphone amplifier. Due to its wide operating supply voltage, the RC4580-Q1 device can also be used in low-voltage applications.

ORDERING INFORMATION(1)

T _A	PACK	AGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	SOIC - D	Reel of 2000	RC4580QDRQ1	R4580Q
-40°C to 125°C	TSSOP - PW	Reel of 2000	RC4580QPWRQ1	R4580Q

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Input + Input

Figure 1. EQUIVALENT SCHEMATIC

ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	Supply voltage		±18	V
	Input voltage (any input)		±15	V
V_{ID}	Differential input voltage		±30	V
	Output current		±50	mA
T _A	Ambient temperature range	-40	125	°C
T _{stg}	Storage temperature range	-60	125	°C
Electrostatic	Human-body model (HBM) AEC-Q100 Classification Level H2		2	kV
Discharge (ESD) Ratings	Charged-device model (CDM) AEC-Q100 Classification Level C3B		750	V

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



THERMAL INFORMATION

	THERMAL METRIC(1)	RC45	LINUT	
$\theta_{JA} \qquad \qquad \text{Junction-to-ambient thermal resistance} \\ \theta_{JCton} \qquad \text{Junction-to-case (top) thermal resistance}$		D (8 PINS)	PW (8 PINS)	UNIT
θ_{JA}	Junction-to-ambient thermal resistance	109	163	
θ_{JCtop}	Junction-to-case (top) thermal resistance	55.7	38	
θ_{JB}	Junction-to-board thermal resistance	49	90.6	00044
ΨЈТ	Junction-to-top characterization parameter	10.6	1.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	48.6	88.9	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	n/a	n/a	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V _{CC+}	Cumhuualtaga	2	16	V
V _{CC} -	Supply voltage		-16	V
V_{ICR}	Input common-mode voltage range	-13.5	13.5	V
T _A	Operating free-air temperature	-40	125	°C

ELECTRICAL CHARACTERISTICS

 $V_{CC+} = \pm 15 \text{ V}$, $T_A = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IO}	Input offset voltage	$R_S = < 10 \text{ k}\Omega$		0.5	3	mV
I _{IO}	Input offset current			5	200	nA
I _{IB}	Input bias current			100	500	nA
A _{VD}	Large-signal differential voltage amplification	$R_L \ge 2 k\Omega$, $V_O = \pm 10 V$	90	110		dB
V _{CM}	Output voltage swing	$R_L \ge 2 k\Omega$	±12	±13.5		V
V_{ICR}	Common-mode input voltage		±12	±13.5		V
CMRR	Common-mode rejection ratio	$R_S \le 10 \text{ k}\Omega$	80	110		dB
k _{SVR}	Supply-voltage rejection ratio (1)	R _S ≤ 10 kΩ	80	110		dB
I _{CC}	Total supply current (all amplifiers)			6	9	mA

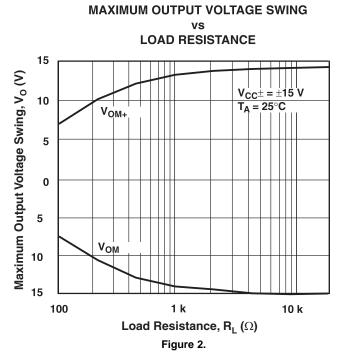
⁽¹⁾ Measured with $V_{CC\pm}$ varied simultaneously

OPERATING CHARACTERISTICS

 $V_{CC\pm} = \pm 15 \text{ V}, T_A = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C} \text{ (unless otherwise noted)}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
SR	Slew rate at unity gain	$R_L \ge 2 k\Omega$	5	V/µs
GBW	Gain-bandwidth product	f = 10 kHz	12	MHz
THD	Total harmonic distortion	$V_{O} = 5 \text{ V}, R_{L} = 2 \text{ k}\Omega, f = 1 \text{ kHz}, A_{VD} = 20 \text{ dB}$	0.0005%	
Vn	Equivalent input noise voltage	RIAA, $R_S \le 2.2 \text{ k}\Omega$, 30-kHz LPF	0.8	μVrms

TYPICAL CHARACTERISTICS



MAXIMUM OUTPUT VOLTAGE SWING vs FREQUENCY

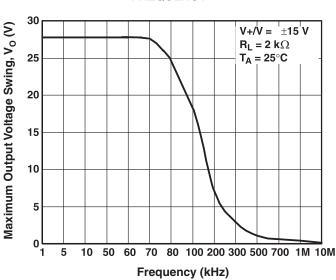
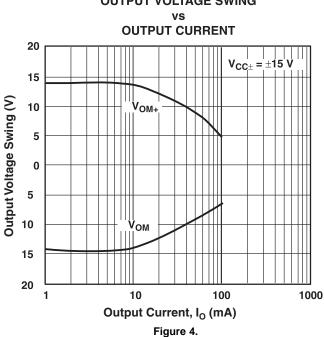
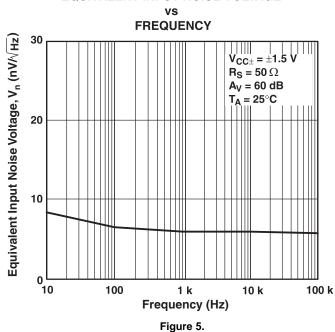


Figure 3.





EQUIVALENT INPUT NOISE VOLTAGE

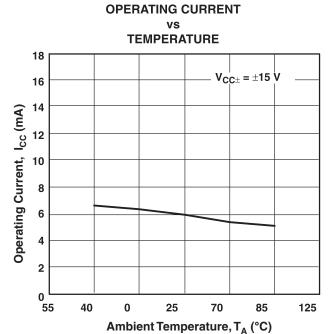


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TYPICAL CHARACTERISTICS (continued)



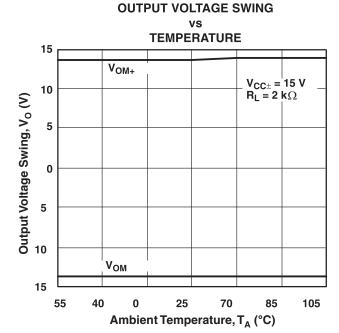
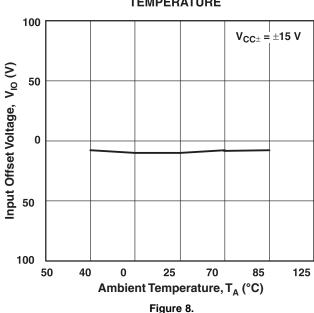


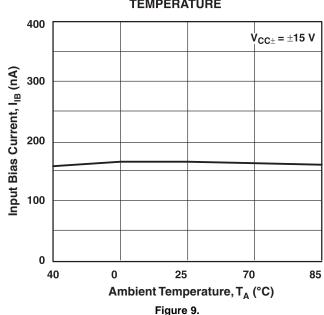


Figure 6.



INPUT BIAS CURRENT vs TEMPERATURE

Figure 7.



TYPICAL CHARACTERISTICS (continued)

MAXIMUM OUTPUT VOLTAGE SWING

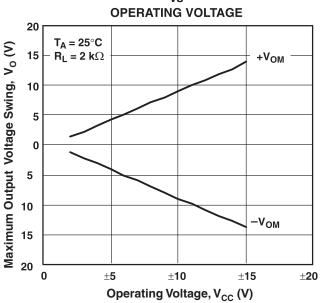
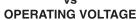


Figure 10.

OPERATING CURRENT



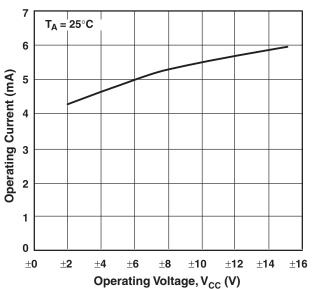
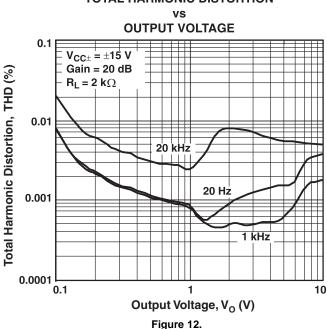
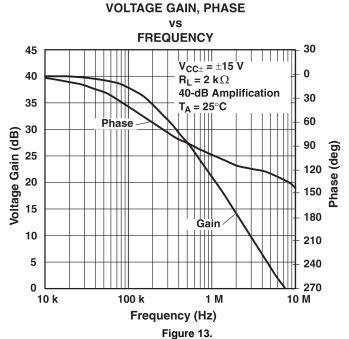


Figure 11.

TOTAL HARMONIC DISTORTION







REVISION HISTORY

CI	hanges from Original (December 2010) to Revision A	Page
•	Added AEC-Q100 info to the features; changed Suitable for Applications to Suitable for Automotive Applications	1
•	Added PW pinout drawing	1
•	Added second row for PW package to Ordering Information table	1
•	Added ESDS	<mark>2</mark>
•	Changed T _J to T _A	<mark>2</mark>
•	Removed θ _{JA} row from Abs Max table because it is also listed in the thermal table	2
•	Added ESD ratings to Abs Max table	2
•	Added thermal table	3
•	Changed $T_A = 25$ °C to $T_A = -40$ °C to 125 °C in condition statement for Elec Char table and Op Char table	3



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp (3)
RC4580QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM
RC4580QPWRQ1	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including to do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in spreference these types of products as "Pb-Free".

RoHS Exempt: Ti defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: Ti defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000pp flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a lie of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/files if the finish value exceeds the maximum column width.

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Addendum-Page 1



OTHER QUALIFIED VERSIONS OF RC4580-Q1:

● Catalog: RC4580

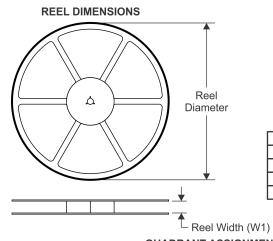
NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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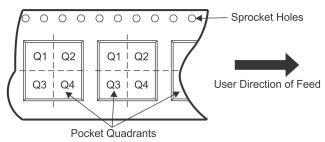
TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity AO Cavity

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

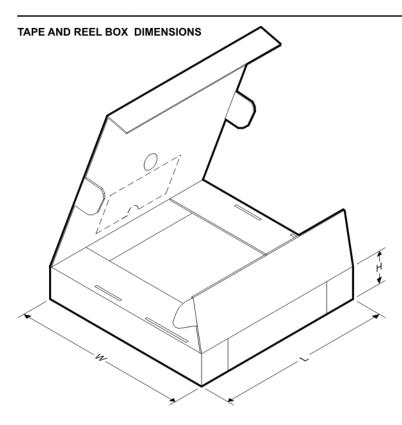


*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
RC4580QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
RC4580QPWRQ1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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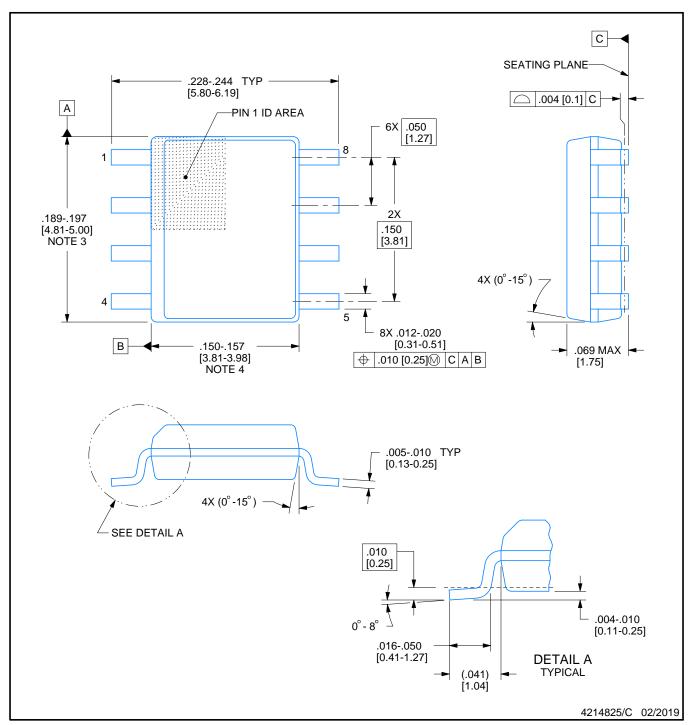
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
RC4580QDRQ1	SOIC	D	8	2500	340.5	336.1	25.0
RC4580QPWRQ1	TSSOP	PW	8	2000	853.0	449.0	35.0

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

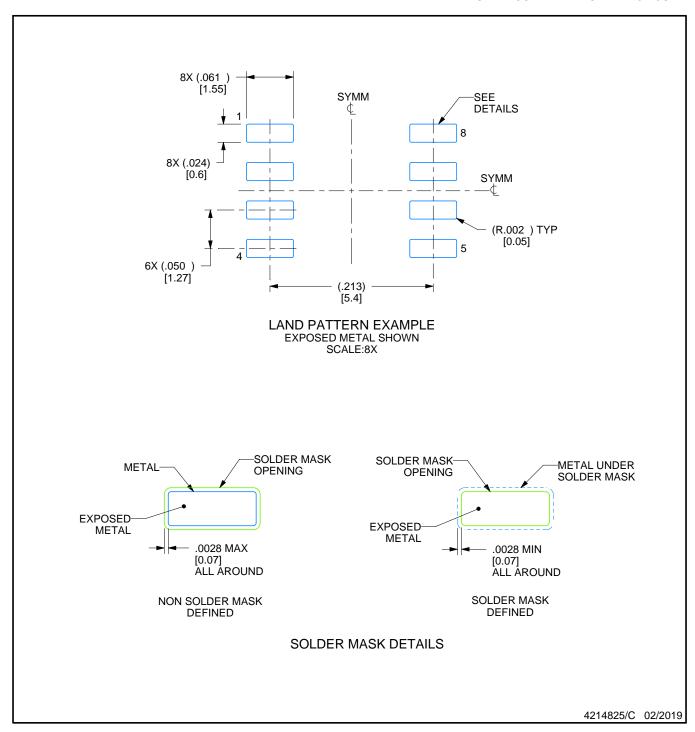


NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
 This dimension does not include interlead flash.
 Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



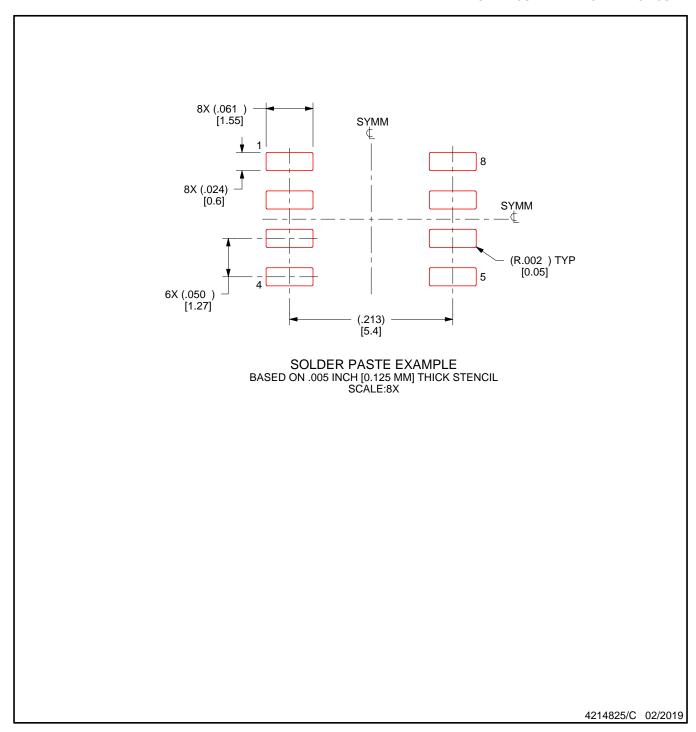
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



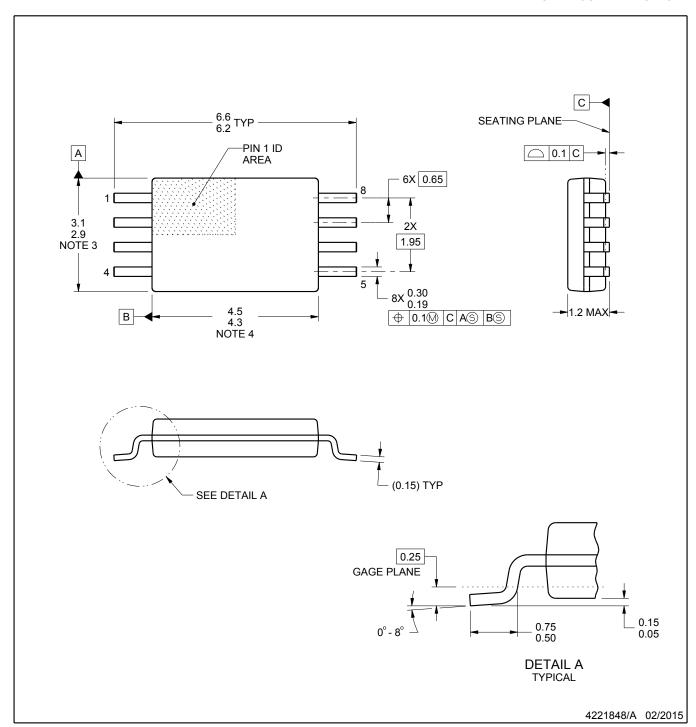
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE

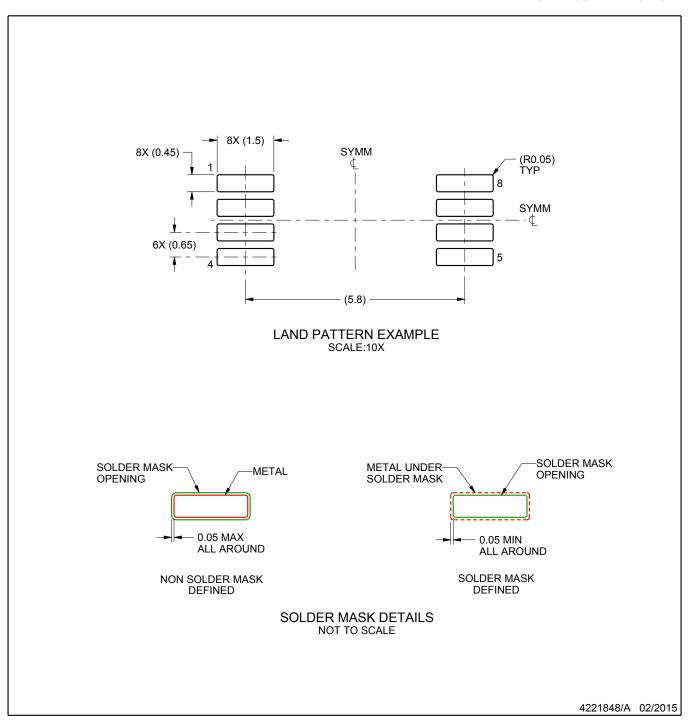


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M
- per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE

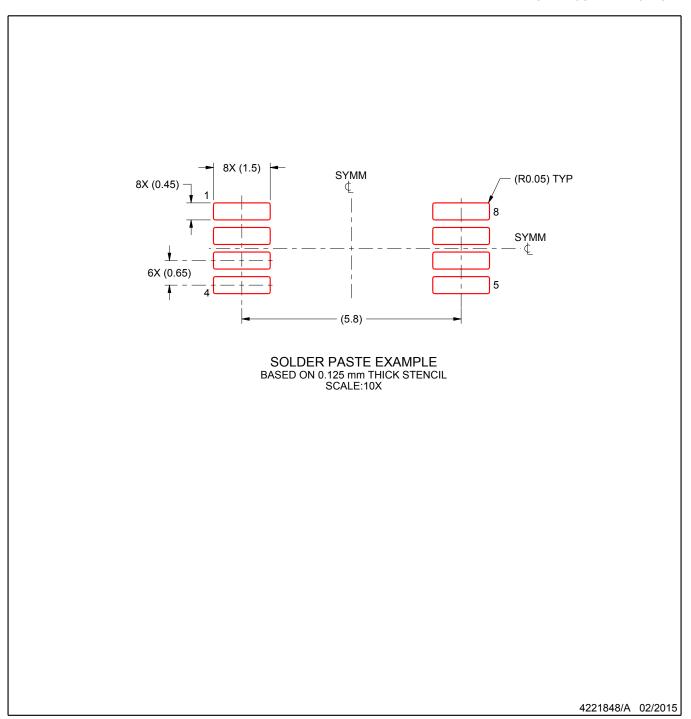


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

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